

WIR SCHAFFEN WISSEN – HEUTE FÜR MORGEN



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Superheavy elements copernicium and flerovium selenides: First Cn-Se bond observation

TASCA 15 – 14th Workshop on Recoil Separator for Superheavy Element Chemistry
GSI, Darmstadt – October 23, 2015

The Superheavy Elements Cn and Fl

IUPAC Periodic Table of the Elements

Key:
 atomic number
Symbol
 name
 standard atomic weight

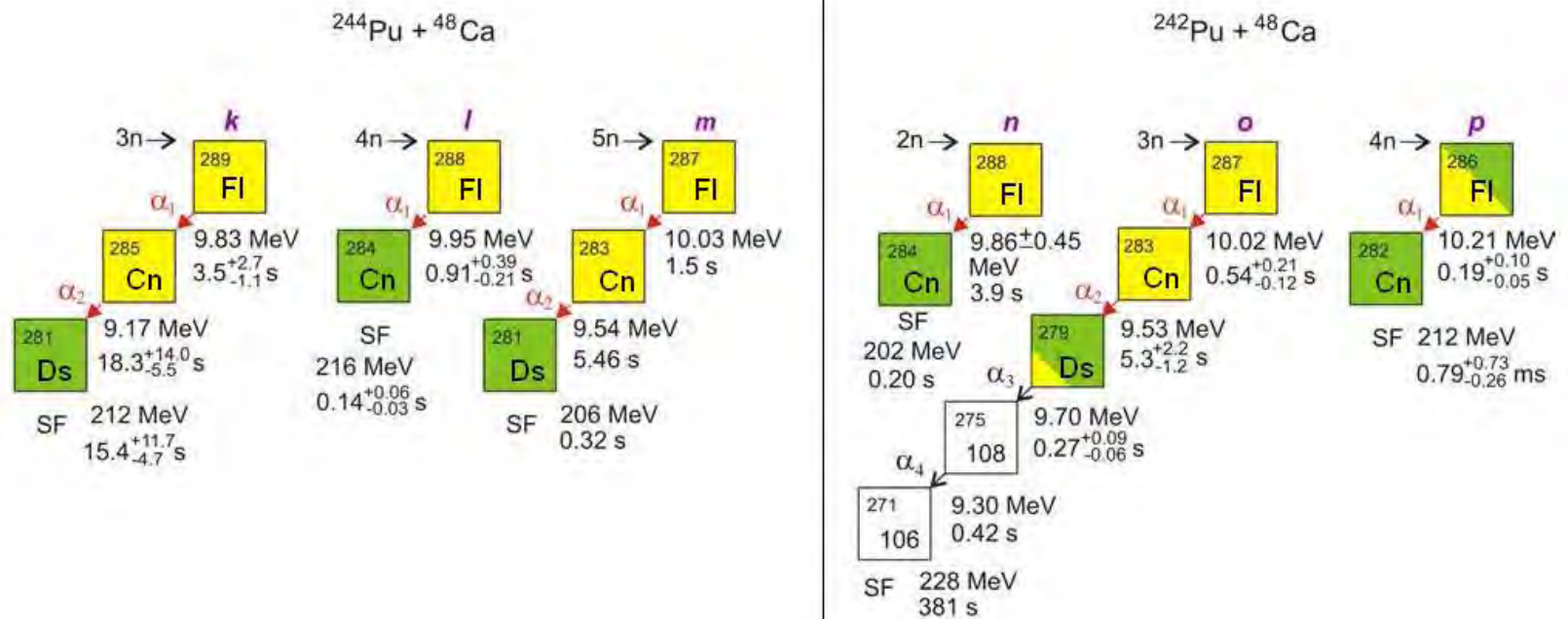
1 H hydrogen (1.007, 1.009)																	2 He helium 4.002
3 Li lithium (6.938, 6.997)	4 Be beryllium 9.012											5 B boron (10.80, 10.83)	6 C carbon (12.00, 12.02)	7 N nitrogen (14.00, 14.01)	8 O oxygen (15.99, 16.00)	9 F fluorine 19.00	10 Ne neon 20.18
11 Na sodium 22.99	12 Mg magnesium (24.30, 24.31)											13 Al aluminum 26.98	14 Si silicon (28.08, 28.09)	15 P phosphorus 30.97	16 S sulfur (32.05, 32.08)	17 Cl chlorine (35.44, 35.46)	18 Ar argon 39.95
19 K potassium 39.10	20 Ca calcium 40.08	21 Sc scandium 44.96	22 Ti titanium 47.87	23 V vanadium 50.94	24 Cr chromium 52.00	25 Mn manganese 54.94	26 Fe iron 55.85	27 Co cobalt 58.93	28 Ni nickel 58.69	29 Cu copper 63.55	30 Zn zinc 65.38(2)	31 Ga gallium 69.72	32 Ge germanium 72.63	33 As arsenic 74.92	34 Se selenium 78.96(3)	35 Br bromine (79.90, 79.91)	36 Kr krypton 83.80
37 Rb rubidium 85.47	38 Sr strontium 87.62	39 Y yttrium 88.91	40 Zr zirconium 91.22	41 Nb niobium 92.91	42 Mo molybdenum 95.96(2)	43 Tc technetium	44 Ru ruthenium 101.1	45 Rh rhodium 102.9	46 Pd palladium 106.4	47 Ag silver 107.9	48 Cd cadmium 112.4	49 In indium 114.8	50 Sn tin 118.7	51 Sb antimony 121.8	52 Te tellurium 127.6	53 I iodine 126.9	54 Xe xenon 131.3
55 Cs cesium 132.9	56 Ba barium 137.3	57-71 lanthanoids	72 Hf hafnium 178.5	73 Ta tantalum 180.9	74 W tungsten 183.8	75 Re rhenium 186.2	76 Os osmium 190.2	77 Ir iridium 192.2	78 Pt platinum 195.1	79 Au gold 197.0	80 Hg mercury 200.6	81 Tl thallium (204.3, 204.4)	82 Pb lead 207.2	83 Bi bismuth 208.0	84 Po polonium	85 At astatine	86 Rn radon
87 Fr francium	88 Ra radium	89-103 actinoids	104 Rf rutherfordium	105 Db dubnium	106 Sg seaborgium	107 Bh bohrium	108 Hs hassium	109 Mt meitnerium	110 Ds darmstadtium	111 Rg roentgenium	112 Cn copernicium	113	114 Fl flerovium	115	116 Lv livermorium	117	118
57 La lanthanum 138.9	58 Ce cerium 140.1	59 Pr praseodymium 140.9	60 Nd neodymium 144.2	61 Pm promethium	62 Sm samarium 150.4	63 Eu europium 152.0	64 Gd gadolinium 157.3	65 Tb terbium 158.9	66 Dy dysprosium 162.5	67 Ho holmium 164.9	68 Er erbium 167.3	69 Tm thulium 168.9	70 Yb ytterbium 173.1	71 Lu lutetium 175.0			
89 Ac actinium	90 Th thorium 232.0	91 Pa protactinium 231.0	92 U uranium 238.0	93 Np neptunium	94 Pu plutonium	95 Am americium	96 Cm curium	97 Bk berkelium	98 Cf californium	99 Es einsteinium	100 Fm fermium	101 Md mendelevium	102 No nobelium	103 Lr lawrencium			



INTERNATIONAL UNION OF
PURE AND APPLIED CHEMISTRY

For updates to this table, see iupac.org/reports/periodic_table/. This version is dated 11 May 2013.
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Production and identification of Cn and Fl



The possibility of **simultaneous production** of Cn and Fl gives the chance of perform **comparative studies**.

Selenium as stationary surface

VON SZENTPÁLY L., "Predictions of the Sublimation Enthalpies of Group 12 Chalcogenides and the Formation Enthalpies of their Polonides", *The Journal of Physical Chemistry A*, 2008, 112.49: 12695-12701; HAYNES W.M., LIDE D.R., BRUNO T.J., "CRC Handbook of Chemistry and Physics 2012-2013", CRC press; BOONE S., KLEPPA O.J., "Enthalpies of formation for Group IV selenides (GeSe_2 , $\text{GeSe}_{2(\text{am})}$, SnSe , SnSe_2 , PbSe) by direct-combination drop calorimetry", *Thermochemica Acta*, 1992, 197. 1, 109-121; P.A.G. O'HARE, SUSMAN S., VOLIN K.J., "Thermochemistry of germanium monoselenide, and the GeSe bond dissociation enthalpy", *The Journal of Chemical Thermodynamics*, 1989, 21.8: 827-836.

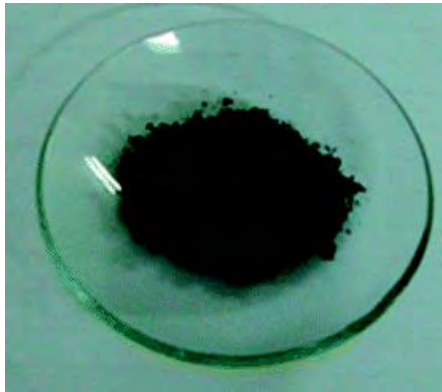
Se major allotropes



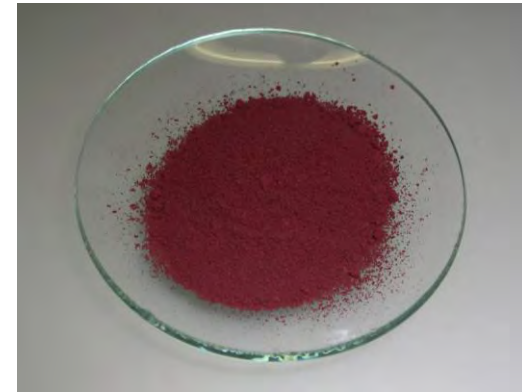
trigonal



monoclinic (α -, β -, γ -Se)

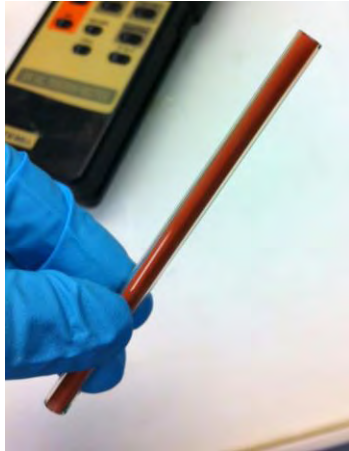


black amorphous Se

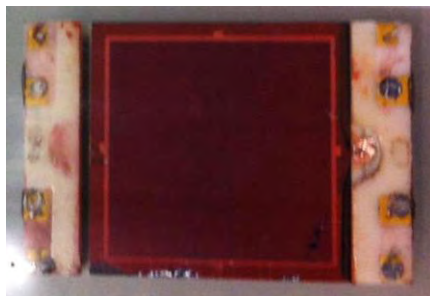


red amorphous Se

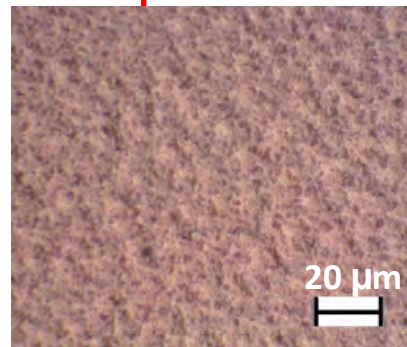
Red a-Se covered columns and PIN diodes



red a-Se coated column

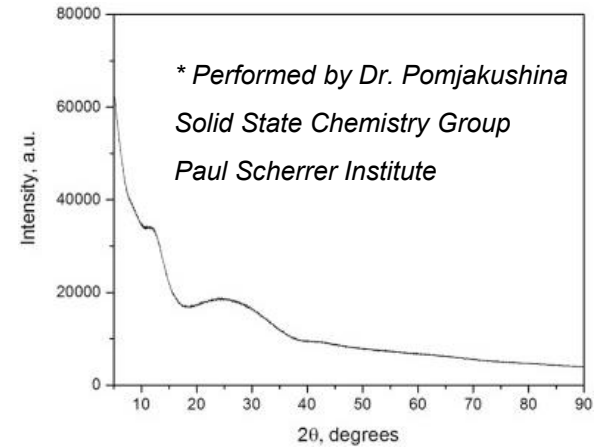


red a-Se coated PIN diode

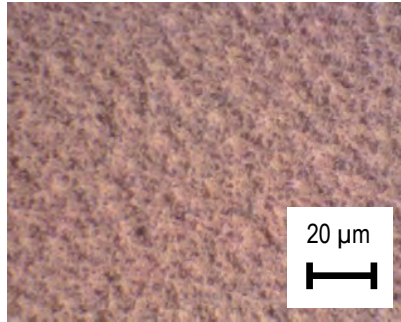


X-ray diffraction

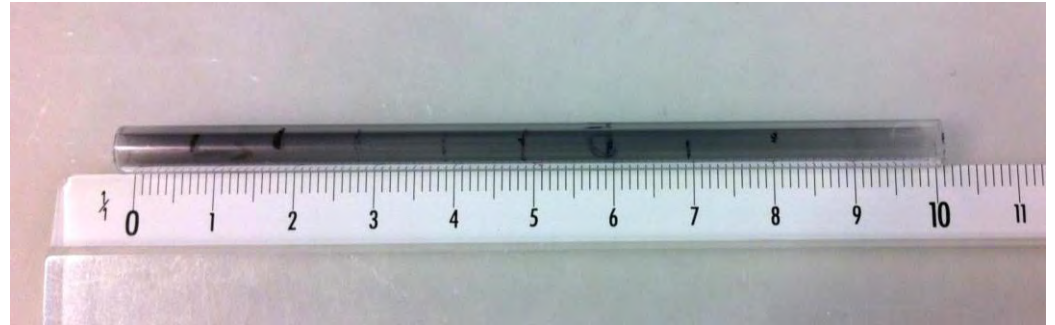
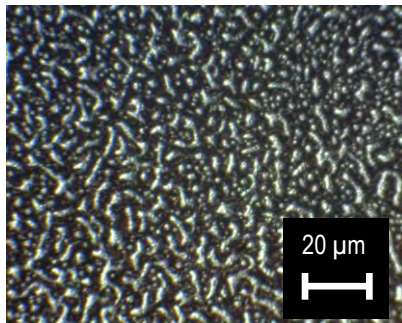
alpha spectroscopy



Trigonal Se covered columns and PIN diodes



- step 1: 100 °C
- step 2: 110 °C
- step 3: 150 °C
- step 4: CS₂ dissolution



trigonal Se coated column



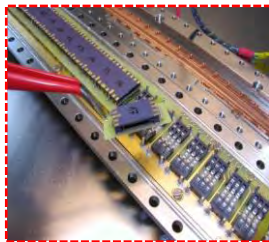
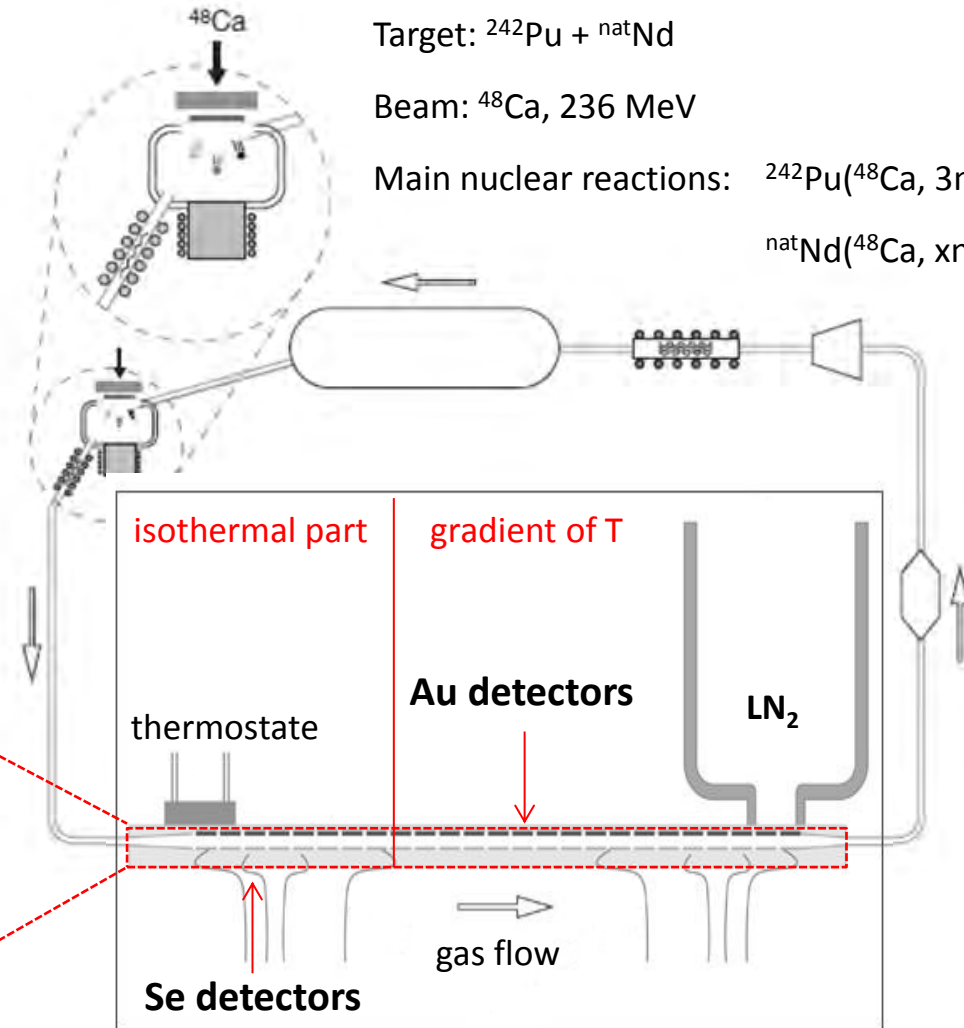
trigonal Se coated PIN diode



Different allotrope, diverse reactivity

Isothermal chromatography, T = 23 °C

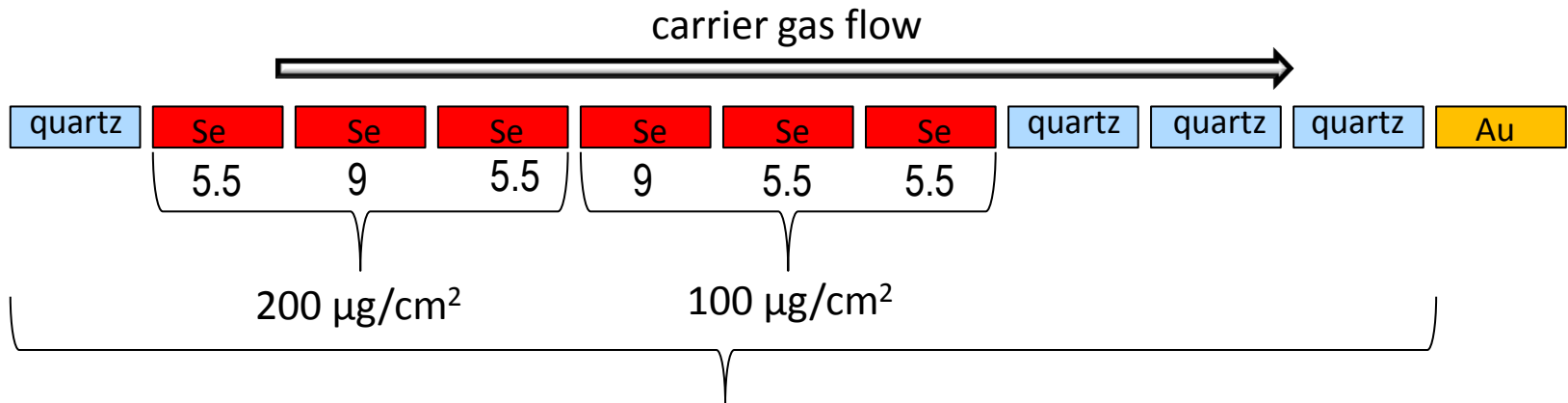
Preliminary results



Red a-Se covered PIN diodes

- 5 diodes **100 $\mu\text{g}/\text{cm}^2$** in thickness
 - } 2 diodes aged **9 weeks**
 - } 3 diodes aged **5.5 weeks**

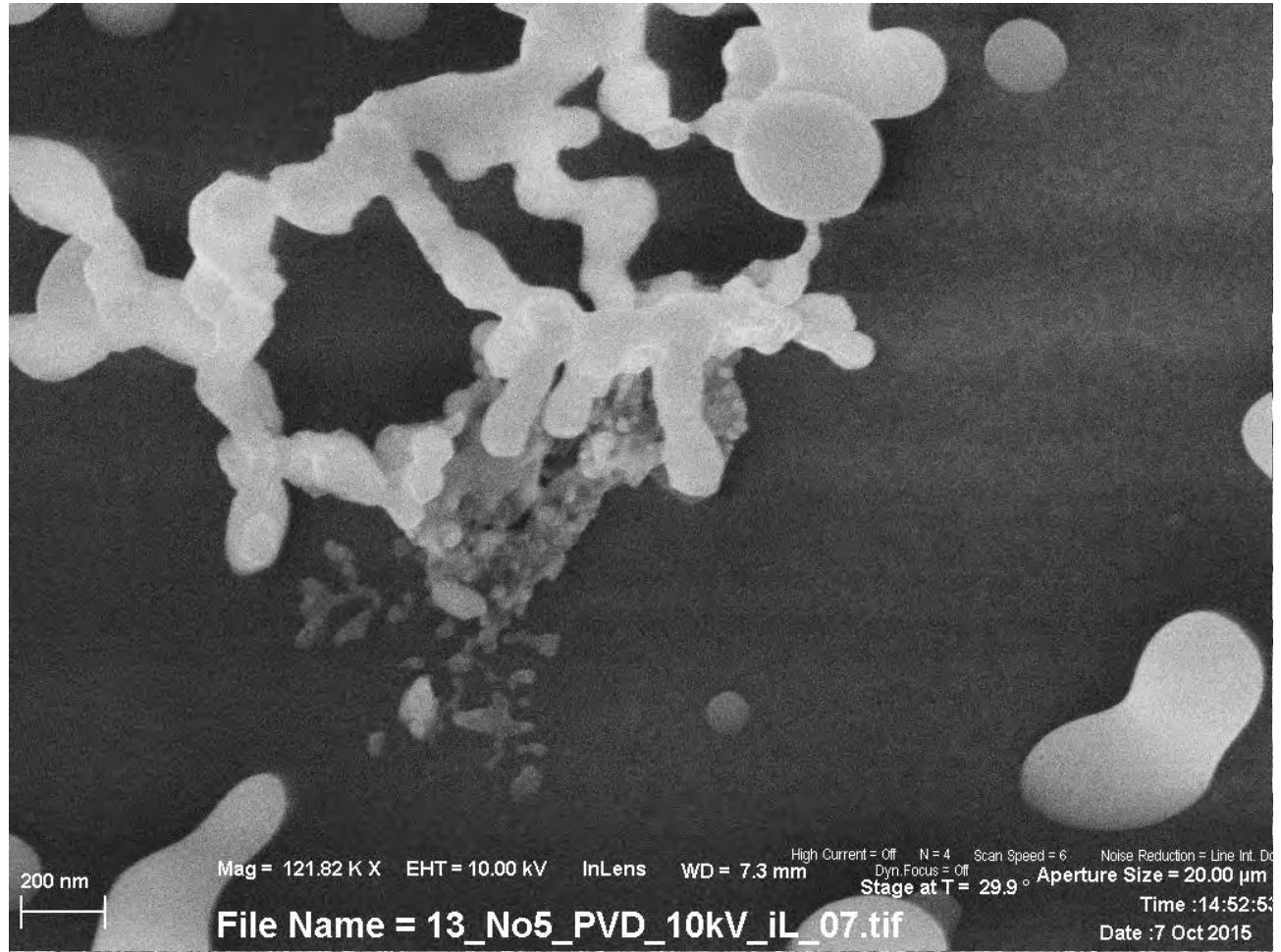
- 6 diodes **200 $\mu\text{g}/\text{cm}^2$** in thickness
 - } 3 diodes aged **9 weeks**
 - } 3 diodes aged **5.5 weeks**



First 10 detectors, isothermal part of the COLD array

Preliminary results

Se surface scanning electron microscopy (SEM)





Se surface X-ray diffraction (XRD)

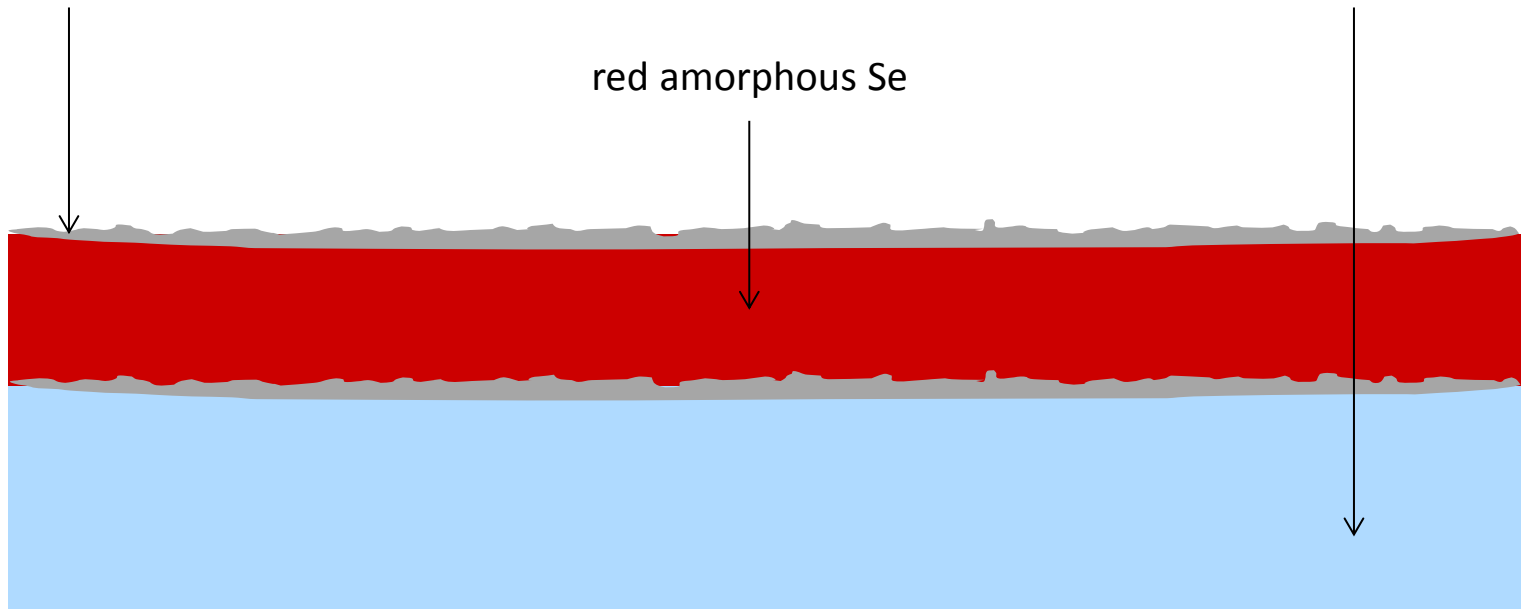


The Se crystallization occurs at the interfaces

crystallized Se < 2% of the Se sample (LOD)

substrate (quartz)

red amorphous Se

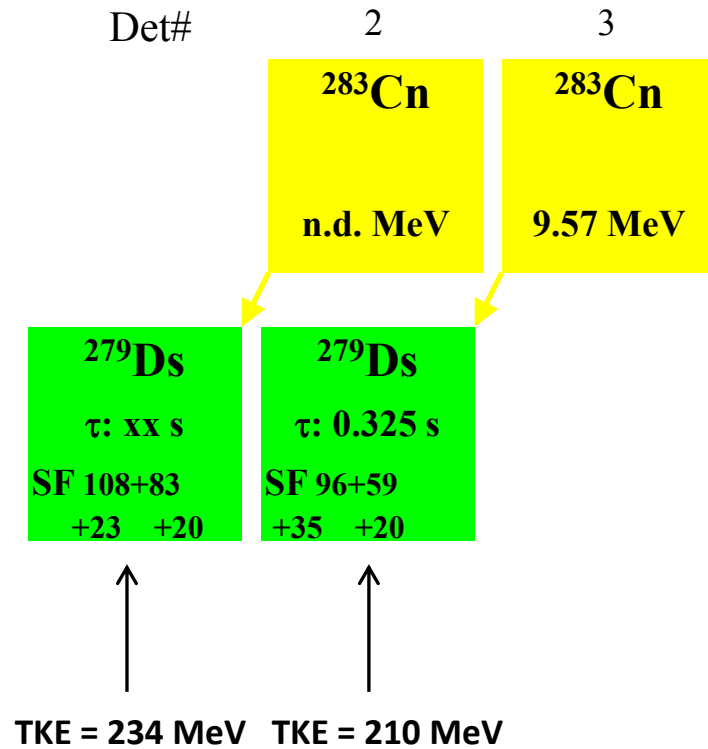


XRD is not enough sensitive to analyze the surface morphology.

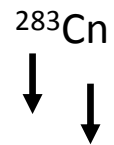
Grazing Incidence X-ray diffraction (**GIXRD**)?

KIM, K.S., et al. "Crystallization of amorphous selenium films. I. Morphology and kinetics". J. Appl. Phys., 1973, 44.12: 5237-5244; CLEMENT, R., et al. "The photo-crystallization of amorphous selenium thin films" J. Non-Cryst. Solids, 1974, 15.3: 505-516; LEGROS, A., et al. "Effect on water impurity on the crystallization of vacuum evaporated Se", J. Appl. Phys., 1995, 78.5: 3048-3051

Cn events on Se detectors

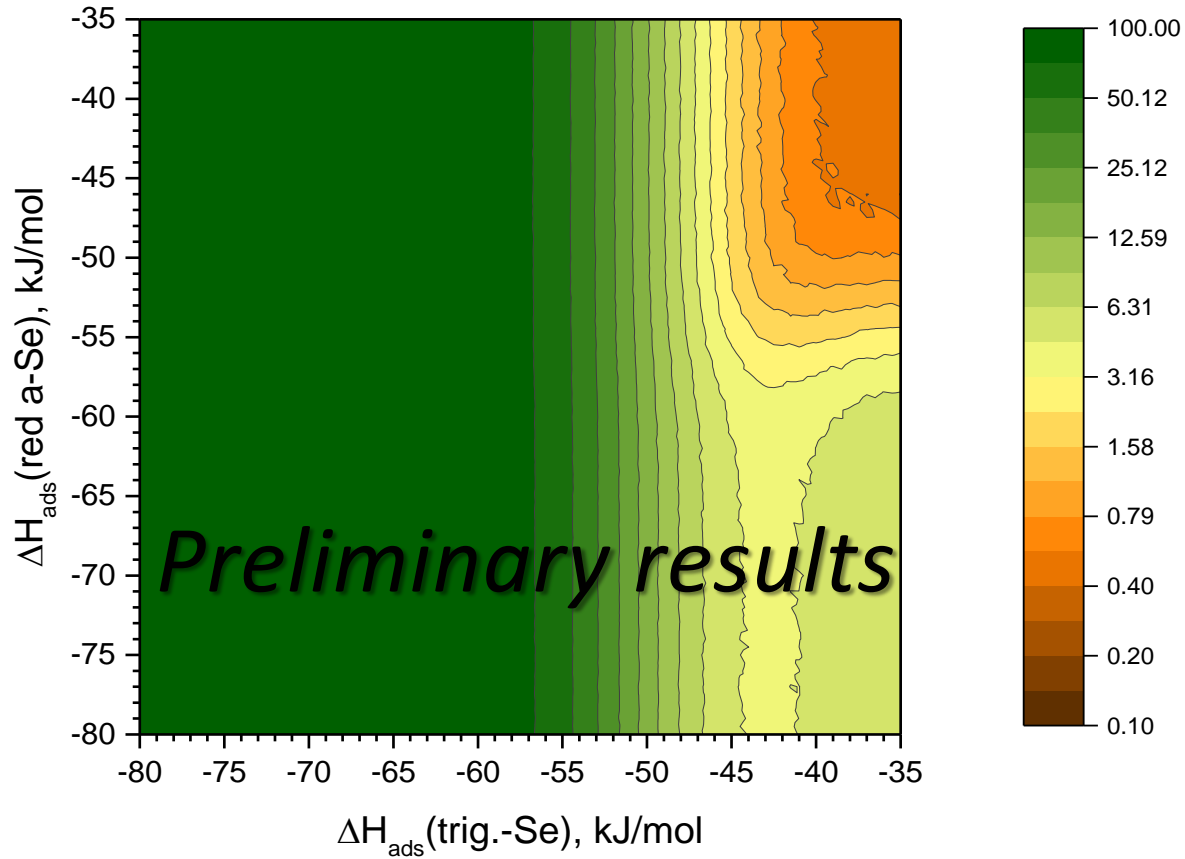


Cn events on Se detectors



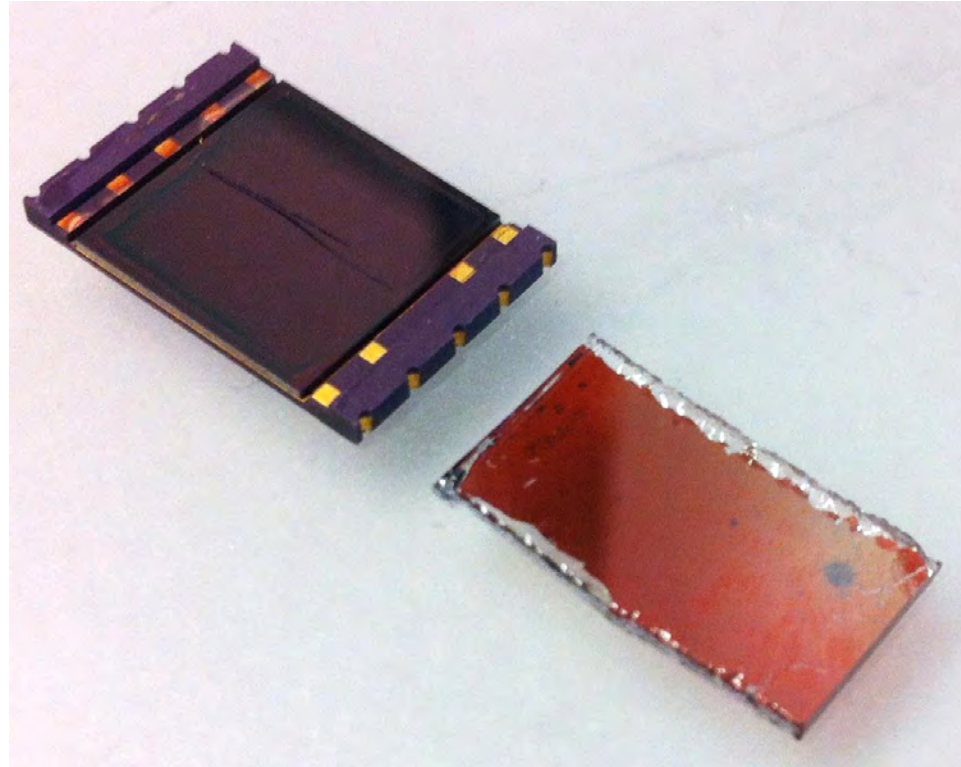
Preliminary results

Se diodes coverage: 5% red a-Se, 90 % t-Se



Cn reacted with trigonal Se with a probability >95%, with a $-\Delta H_{\text{ads}} > 48 \text{ kJ/mol}$

Se vacuum evaporation PIN diodes coverage



Next steps:

- crystallization studies (**storage time**) through ^{197}Hg deposition
- **resolution** and layer thickness calculation through **alpha spectroscopy** and **AASifit simulations**

- ❑ The **Se surface crystallization** can be **monitored** by **Hg deposition**

- ❑ A severe **kinetic hindrance** of the **Hg / trigonal Se** reaction is confirmed

- ❑ First indication that the **interaction of Cn with Se is more favored**, if compared to the Hg / trigonal Se system

- ❑ **Inverse thermochromatographic studies** will be performed to understand the **kinetic** process of the **Hg/Se interaction**. Hopefully an activation energy will be derived.

- ❑ Future **on-line experiments** are envisaged to:
 - confirm the Cn chemical behavior on trigonal Se surfaces
 - assess the chemical behavior of Cn on red amorphous surfaces
 - assess the chemical behavior of FI on both selenium allotropic surfaces

Thanks to:

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Thank you for your kind attention